TLCS-90 Series TMP90C141

CMOS 8-Bit Microcontrollers

TMP90C141N/TMP90C141F

1. Outline and Characteristics

The TMP90C141 is a high-speed advanced 8-bit microcontroller applicable to a variety of equipment.

With its 8-bit CPU, A/D converter, multi-function timer/ event counter and general-purpose serial interface integrated into a single CMOS chip, the TMP90C041 allows the expansion of external memories for programs (up to 64K byte) and data (1M byte).

The TMP90C141N is a 64-pin shrink DIP product. (SDIP64-P750)

The TMP90C041F is a 64-pin flat package product. (QFP64-P1420A)

The characteristics of the TMP90C141 include:

- (1) Powerful instructions: 163 basic instructions, including Multiplication, division, 16-bit arithmetic operations, bit manipulation instructions
- (2) Minimum instruction executing time:320ns (at 12.5MHz oscillation frequency)

- (3) Internal RAM
- (4) Memory expansionExternal program memory: 63K byteExternal data memory: 1M byte
- (5) 8-bit A/D converter (6 channels)
- (6) General-purpose serial interface (1 Channel) Asynchronous mode, I/O interface mode
- (7) Multi-function 16-bit timer/event counter (1 channel)
- (8) 8-bit timers (4 channels)
- (9) Stepping motor control port (2 channels)
- (10) Input/Output ports (28 pins)
- (11) Interrupt function:10 internal interrupts and 4 external interrupts
- (12) Micro Direct Memory Access (µDMA) function (11 channels)
- (13) Watchdog timer
- (14) Standby function (4 HALT modes)

The information contained herein is presented only as guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others. These TOSHIBA products are intended for usage in general electronic equipments (office equipment, communication equipment, measuring equipment, domestic electrification, etc.) Please make sure that you consult with us before you use these TOSHIBA products in equipments which require high quality and/or reliability, and in equipments which could have major impact to the welfare of human life (atomic energy control, spaceship, traffic signal, combustion control, all types of safety devices, etc.). TOSHIBA cannot accept liability to any damage which may occur in case these TOSHIBA products were used in the mentioned equipments without prior consultation with TOSHIBA.

TOSHIBA CORPORATION 1/12

The information contained here is subject to change without notice.

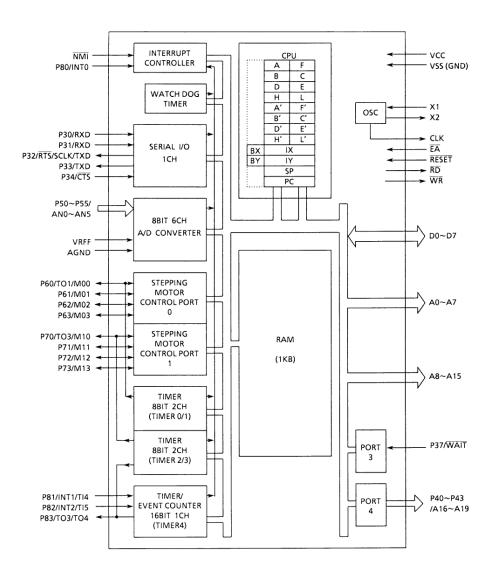


Figure 1. TMP90C141 Block Diagram

2. Pin Assignment and Functions

2.1 Pin Assignment

The assignment of input/output pins, their names and functions are described below.

Figure 2.1 (1) shows pin assignment of the TMP90C141N.

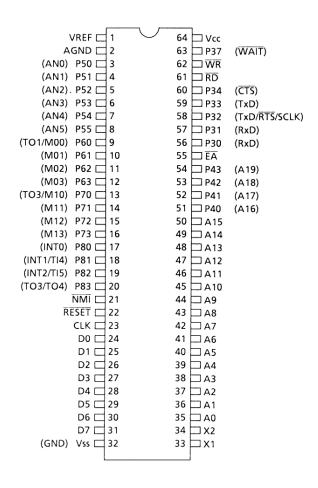


Figure 2.1 (1). Pin Assignment (Shrink Dual Inline Package)

Figure 2.1 (2) shows pin assignment of

theTMP90C141F.

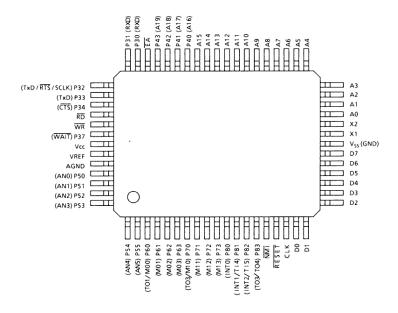


Figure 1. 1 (2). Pin Assignment (Flat Package)

2.2 Pin Names and Functions

rized in Table 2.2.

The names of input/output pins and their functions are summa-

Table 2.2 Pin Names and Functions (1/2)

Pin Name	No. of pins	I/O 3 states	Function
D0 ~ D7	8	3 states	Data bus: Also functions as 8-bit bidirectional data bus for external memory
A0 ~ A7	8	Output	Address bus: The lower 8 bits address bus for external memory
A8 ~ A15	8	Output	Address bus: The upper 8 bits address bus for external memory
P30	1	Input	Port 30: 1-bit input port
/RxD	1	Прис	Receiver Serial Data
P31	1	Input	Port 31: 1-bit input port
/RxD	ı	IIIput	Receiver Serial Data
P32			Port 32: 1-bit input port
/TxD	1	Output	Transmitter Serial Data
/RTS /SCLK	!	Output	Request to send Serial Data
/SULK			Serial clock output
P33	1	Output	Port 33: 1-bit output port
/TxD	!	Output	Transmitter Serial Data
P34	1	Input	Port 34: 1-bit input port
/CTS	1	mpat	Clear to send Serial data
RD	1	Output	Read: Generates strobe signal for reading external memory
WR	1	Output	Write: Generates strobe signal for writing into external memory
<u>P37</u>	1	Input	Port 37: 1-bit input port
/WAIT	ı ı	IIIput	Wait: Input pin for connecting slow speed memory or peripheral LSI
P40 ~ P43			Port 4: 4-bit output port that allows selection of Port/Address Bus on bit basis
/A16 ~ A19	4	Output	Address bus: Also functions as address bus for external memory (4 bits of bank address)

Table 2.2 Pin Names and Functions (2/2)

Pin Name	No. of Pins	I/O 3 states	Function
P50 ~ P55	C	lanut	Port 5: 6-bit input port
/AN0 ~ AN5	6	Input	Analog input: 6 analog input to A/D converter
VREF	1	-	Input of reference voltage to A/D converter
AGND	1	_	Ground pin for A/D converter
P60 ~ P63		1/0	Port 6: 4-bit I/O port that allows I/O selection on bit basis
/M00 ~ M03	4	Output	Stepping motor control port 0
/T01		Output	Timer output 1: Output of Timer 0 or 1
P70 ~ P73		1/0	Port 7: 4-bit I/O port that allows I/O selection on bit basis
/M10 ~ M13	4	Output	Stepping motor control port 1
/T03		Output	Timer output 3: Output of timer 2 or 3
			Port 80: 1-bit input port
P80			Interrupt request pin 0: Interrupt request pin (Level/rising edge is
/INTO	1	Input	programmable)
			Port 81: 1-bit input port
P81			Interrupt request pin 1: Interrupt request pin (Rising/falling edge is
/INT1	1	Input	programmable)
/TI4			
			Timer input 4: Counter/capture trigger signal for Timer 4
P82			Port 82: 1-bit input port
/INT2	1	Input	Interrupt request pin 2: rising edge interrupt request pin
/TI5			Timer input 5: capture trigger signal for Timer 4
P82	4	0.44	Port 83: 1-bit output port
/T03/T04	1	Output	Timer output 3/4: Output of Timer 2, 3 or 4
			Non-maskable interrupt request pin: Falling edge interrupt request pin
NMI	1	Input	
CLK	1	Output	Clock output: Generates clock pulse at 1/4 frequency of clock oscillation. It is
ULN	l l	Output	Pulled up internally during resetting.
ĒΑ	1	Input	External access: Connects with GND pin in the TMP90C141 with no internal
RESET	1	· ·	ROM. Reset: Initializes the TMP90C141. (Built-in pull-up resister)
UESEI	·	Input	
X1/X2	2	Input/ Output	Pin for quartz crystal or ceramic resonator
V _{CC}	1	_	Power supply (+5V)
V _{SS} (GND)	1	_	Ground (OV)

3. Operation

The following explains the TMP90C141 functions and basic operations. The CPU functions and internal I/O functions of the TMP90C141 are the same as the TMP90C840A.

Refer to the "TMP90C840A" section concerning functions which are not explained the following.

3.1 CPU

The TMP90C141 has an internal high-performance 8-bit CPU. Refer to the "TLCS-90 CPU" section concerning CPU operation.

3.2 Memory Map

The TMP90C141 supports a program memory of up to 64K bytes and a data memory of maximum 1M bytes.

The program memory may be assigned to the address space from 00000H to 0FFFFH, while the data memory can be allocated to any address from 00000H to FFFFFH.

(1) Internal RAM

The TMP90C141 internally contains a 1K byte RAM, which is allocated to the address space from FBC0H to FFBFH. The CPU allows the access to a certain RAM area (FF00H to FFBFH, 192 bytes) by a short operation code (opcode) in a "direct addressing mode".

The addresses from FF10H to FF7FH in this RAM area can be used as parameter area for micro DMA processing (and for any other purposes when the micro DMA function is not used).

(2) Internal I/O

The TMP90C141 provides a 48-byte address space as an internal I/O area, whose addressess range from FFC0H to FFEFH. This I/O area can be accessed by the CPU using a short opcode in the "direct addressing mode".

Figure 3.1 is a memory map indicating the areas accessible by the CPU in the respective addressing mode.

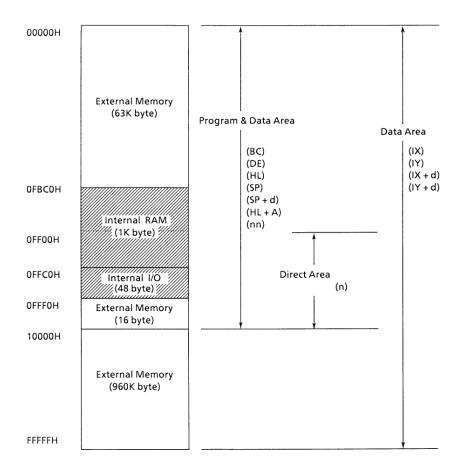


Figure 3.2. Memory Map

4. Electrical Characteristics

TMP90C141N/TMP90C141F

4.1 Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
V _{CC}	Supply voltage	-0.5 ~ + 7	V	
V _{IN}	Input voltage	-0.5 ~ V _{CC} + 0.5	V	
D	Power dissipation (Ta = 70°C)	F 500	mW	
P_{D}	Tower dissipation (1a = 70 G)	N 600	IIIVV	
T _{SOLDER}	Soldering temperature (10s)	260	°C	
T _{STG}	Storage temperature	-65 ~ 150	°C	
T _{OPR}	Operating temperature	-20 ~ 70	°C	

4.2 DC Characteristics

TA = -20 ~ 70°C Vcc = 5V \pm 10% Typical Values are for TA = 25°C and Vcc = 5V.

Symbol	Parameter	Min	Max	Unit	Test Conditions
V _{IL}	Input Low Voltage (D0 ~ D7)	-0.3	0.2V _{CC} - 0.1	V	-
V _{IL1}	P3, P5, P6, P7, P8	-0.3	0.3V _{CC}	V	-
V _{IL2}	RESET, INTO, NMI	-0.3	0.25V _{CC}	V	-
V_{IL4}	X1	-0.3	0.2V _{CC}	V	-
V _{IH}	Input Low Voltage (D0 ~ D7)	0.2V _{CC} + 1.1	V _{CC} + 0.3	V	-
V _{IH1}	P3, P5, P6, P7, P8	0.7V _{CC}	V _{CC} + 0.3	V	-
V _{IH2}	RESET, INTO, NMI	0.75V _{CC}	V _{CC} + 0.3	V	-
V _{IH4}	X1	0.8V _{CC}	V _{CC} + 0.3	V	-
V _{OL}	Output Low Voltage	-	0.45	V	I _{OL} = 1.6mA
V _{OH} V _{OH1} V _{OH2}	Output High Voltage	2.4 0.75V _{CC} 0.9V _{CC}	-	V V V	I _{OH} = -400μA I _{OH} = -100μA I _{OH} = -20μA
I _{DAR}	Darlington Drive Current (8 I/O pins)	-1.0	-3.5	mA	$V_{EXT} = 1.5V$ $R_{EXT} = 1.1k\Omega$
I _{LI}	Input Leakage Current	0.02 (Typ)	±5	μA	0.0 ≤ Vin ≤ V _{CC}
I_{L0}	Output Leakage Current	0.05 (Typ)	±10	μA	0.2 ≤ Vin ≤ V _{CC} - 0.2
I _{CC}	Operating Current (RUN) Idle 1 Idle 2	20 (Typ) 1.5 (Typ) 9 (Typ)	30 5 15	mA mA mA	tosc = 12.5MHz
	STOP (TA = -20 ~ 70°C) STOP (TA = 0 ~ 50°C)	0.2 (Typ)	50 10	μΑ μΑ	0.2 ≤ Vin ≤ V _{CC} - 0.2
R _{RST}	RESET Pull Up Register	50	150	ΚΩ	-
CIO	Pin Capacitance	_	10	pF	testfreq = 1MHz
V _{TH}	Schmitt width RESET, NMI, INTO	0.4	1.0 (Typ)	V	_

Note: $\ensuremath{I_{DAR}}$ is guaranteed for a total of up to 8 optional ports.

8/12 TOSHIBA CORPORATION

4.3 AC Characteristics

TA = -20 ~ 70°CV $_{CC}$ = 5V \pm 10% CL = 50pF

0	Downwardow.	Vai	riable	10MH	z Clock	12.5M	llm:4	
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Unit
t _{OSC}	OSC. Period = x	80	1000	100	_	80	_	ns
t _{CYC}	CLK Period	4x	4x	400	-	320	-	ns
t _{WL}	CLK Low width	2x - 40	-	160	-	120	-	ns
t _{WH}	CLK High width	2x - 40	-	160	_	120	_	ns
t_{AC}	Address Setup to RD, WR	x - 45	-	55	-	35	_	ns
t _{RR}	RD Low width	2.5x - 40	-	210	-	160	-	ns
t _{CA}	Address Hold Time After RD, WR	0.5x - 30	-	20	-	10	-	ns
t _{AD}	Address to Valid Data In	-	3.5x - 95	-	255	-	185	ns
t _{RD}	RD to Valid Data In	-	2.5x - 80	-	170	-	120	ns
t _{HR}	Input Data Hold After RD	0	-	0	-	0	_	ns
t _{ww}	WR Low width	2.5x - 40	-	210	-	160	-	ns
t _{DW}	Data Setup to WR	2x - 50	-	150	_	110	_	ns
t _{WD}	Data Hold After WR	30	90	30	90	30	90	ns
t _{CWA}	RD, WR to Valid WAIT	_	1.5x - 100	-	50	-	20	ns
t _{AWA}	Address to Valid WAIT	_	2.5x - 130	-	120	-	70	ns
t _{WAS}	WAIT Setup to CLK	70	_	70	-	70	_	ns
t _{WAH}	WAIT Hold After CLK	0	-	0	_	0	_	ns
t _{RV}	RD/WR Recovery Time	1.5x - 35	-	115	-	85	_	ns
t _{CPW}	CLK to Port Data Output	_	x + 200	_	300	_	280	ns
t _{PRC}	Port Data Setup to CLK	200	-	200	-	200	_	ns
t _{CPR}	Port Data Hold After CLK	100	_	100	_	100	_	ns
t _{CHCL}	RD/WR Hold After CLK	x - 60	_	40	_	20	_	ns
t _{CLC}	RD/WR Setup to CLK	1.5x - 50	_	100	_	70	_	ns
t _{CLHA}	Address Hold After CLK	1.5x - 80	-	70	_	40	-	ns
t _{ACL}	Address Setup to CLK	2.5x - 80	_	170	_	120	_	ns
t _{CLD}	Data Setup to CLK	x - 50	_	50	_	30	_	ns

• AC output level High 2.2V/Low 0.8V

• AC input level High 2.4V/Low 0.45V (D0 - D7)

High $0.8V_{CC}/Low~0.2V_{CC}$ (excluding D0 – D7)

TOSHIBA CORPORATION 9/12

4.4 A/D Conversion Characteristics

TA:	= -20	~ 7	0°C	V_{CC}	= 5\	l±	10%
-----	-------	-----	-----	----------	------	----	-----

Symbol	Parameter	Min	Тур	Max	Unit
V _{REF}	Analog reference voltage	V _{CC} - 1.5	V _{CC}	V _{CC}	
A _{GND}	Analog reference voltage	V _{SS}	V_{SS}	V_{SS}	V
V _{AIN}	Allowable analog input voltage	V _{SS}	_	V _{CC}	
I _{REF}	Supply current for analog reference voltage	_	0.5	1.0	mA
Error	Total error (TA = 25°C, V _{CC} = V _{REF} = 5.0V)	-	-	1.0	LSB
	Total error	-	-	2.5	

4.5 Zero-Cross Characteristics

TA = -20 ~ 70°C V_{CC} = 5V $\pm\,10\%$

Symbol	Parameter	Condition	Min	Max	Unit
V _{ZX}	Zero-cross detection input	AC coupling $C = 0.1 \mu F$	1	1.8	VAC p - p
A _{ZX}	Zero-cross accuracy	50/60Hz sine wave	-	135	mV
F _{ZX}	Zero-cross detection input frequency	-	0.04	1	kHz

4.6 Serial Channel Timing-I/O Interface Mode

TA = -20 ~ 70°C V_{CC} = 5V \pm 10% CL = 50pF

Symbol	Variable Parameter		10MHz	z Clock	12.5MH	Unit		
Syllibul	yiiibui rarailletei	Min	Max	Min	Max	Min	Max	UIII
t _{SCY}	Serial Port Clock Cycle Time	8x	-	800	-	640	-	ns
toss	Output Data Setup SCLK Rising Edge	6x - 150	-	450	_	330	-	ns
t _{OHS}	Output Data Hold After SCLK Rising Edge	2x - 120	-	80	-	40	-	ns
t _{HSR}	Input Data Hold After SCLK Rising Edge	0	-	0	-	0	-	ns
t _{SRD}	SCLK Rising Edge to Input DATA Valid	-	6x - 150	-	450	-	330	ns

4.7 16-bit Event Counter

TA = -20 ~ 70°C V_{CC} = 5V $\pm\,10\%$

Symbol	vmbol Parameter		Variable		10MHz Clock		12.5MHz Clock	
Symbol	i arameter	Min	Max	Min	Max	Min	Max	Unit
t _{VCK}	TI4 clock cycle	8x + 100	-	900	-	740	-	ns
t _{VCKL}	TI4 Low clock pulse width	4x + 40	-	440	-	360	-	ns
t _{VCKH}	TI4 High clock pulse width	4x + 40	-	440	-	360	-	ns

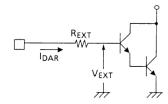
10/12 TOSHIBA CORPORATION

4.8 Interrupt Operation

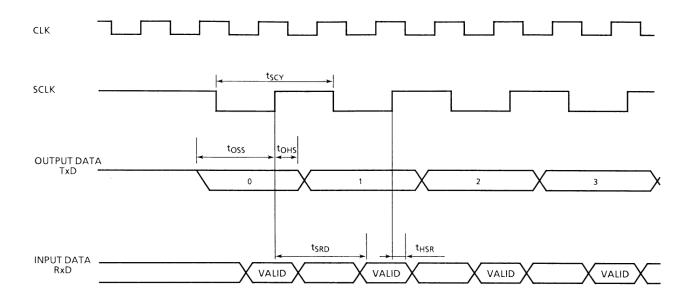
TA = -20 ~ 70°C V_{CC} = 5V \pm 10%

Symbol	Parameter	Variable		10MHz Clock		12.5MHz Clock		Unit
Symbol	raiailletei	Min	Max	Min	Max	Min	Max	Unit
t _{INTAL}	NMI, INTO Low level pulse width	4x	-	400	-	320	-	ns
t _{INTAH}	NMI, INTO High level pulse width	4x	-	400	ı	320	-	ns
t _{INTBL}	INT1, INT2 Low level pulse width	8x + 100	I	900	ı	740	-	ns
t _{INТВН}	INT1, INT2 High level pulse width	8x + 100	-	900	-	740	-	ns

(Reference) Definition of IDAR

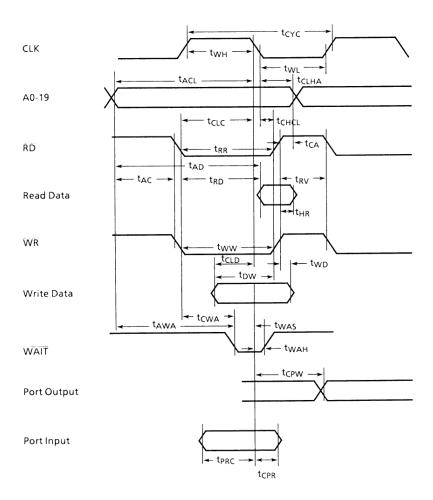


4.9 I/O Interface Mode Timing Chart



TOSHIBA CORPORATION 11/12

4.10 Timing Chart



5. Differences Between TMP90C841A and TMP90C141

Specifications of TMP90C841A and TMP90C141 are the same except below.

Name	TMP90C841A	TMP90C141
RAM	256 bytes of internal RAM are provided. (OFECOH ~ OFFBFH)	1024 bytes of internal RAM are provided. (0FBC0H ~ 0FFBFH)
A0 ~ A15	High-Impedance state during reset	Driving state during reset.
P0 (0FFC1H) P1 (0FFC1H) P2 (0FFC4H)	Provided (same chip as TMP90C840A)	R/W function is not provided.
P01CR (0FFC2H)	Provided	EXT, P1C, P0C is not provided.
P2CR (0FFC5H)	Provided	P2XC register is not provided

^{*} Note: Connect $\overline{\mathsf{EA}}$ pin with GND pin.